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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/614,462	07/07/2003	Tzu-Chiang Sung	252011-1490	7583
47390 7	590 05/31/2005		EXAMINER	
THOMAS, KAYDEN, HOSTEMEYER & RISLEY LLP			LANDAU, MATTHEW C	
100 GALLERIA PARKWAY SUITE 1750		ART UNIT	PAPER NUMBER	
ATLANTA, C	GA 30339		2815	

DATE MAILED: 05/31/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/614,462	SUNG ET AL.			
Office Action Summary	Examiner	Art Unit	-		
	Matthew Landau	2815			
The MAILING DATE of this communication a Period for Reply	appears on the cover sheet w	ith the correspondence address			
A SHORTENED STATUTORY PERIOD FOR REF THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a r - If NO period for reply is specified above, the maximum statutory peri - Failure to reply within the set or extended period for reply will, by state that the period for reply will, by state that the material patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may a reply within the statutory minimum of thi od will apply and will expire SIX (6) MOI tute, cause the application to become A	reply be timely filed ty (30) days will be considered timely. ITHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 09	May 2005.	•			
2a) This action is FINAL . 2b) ⊠ T	his action is non-final.				
3) Since this application is in condition for allow closed in accordance with the practice under the practice under the practice.	•				
Disposition of Claims					
4) ☐ Claim(s) <u>1-3,5,7-11,13,15-17,19,21-25 and</u> 4a) Of the above claim(s) is/are withd 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) <u>1-3,5,7,15-17,19 and 21</u> is/are reje 7) ☐ Claim(s) <u>9-11,13,23-25 and 27</u> is/are object 8) ☐ Claim(s) are subject to restriction and	rawn from consideration. cted. ed to.	lication.			
Application Papers		•			
9)☐ The specification is objected to by the Exami	iner.				
I0)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.					
Applicant may not request that any objection to the	· · · · · · · · · · · · · · · · · · ·	• •			
Replacement drawing sheet(s) including the corr 11) The oath or declaration is objected to by the	,	` ' ').		
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for forei a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the p application from the International Bure * See the attached detailed Office action for a l	ents have been received. ents have been received in A riority documents have beer eau (PCT Rule 17.2(a)).	application No received in this National Stage			
Attachment(s)	·				
1) Notice of References Cited (PTO-892)	4) Interview	Summary (PTO-413)			
 Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date 	Paper No	s)/Mail Date nformal Patent Application (PTO-152)			

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DETAILED ACTION

Response to Amendment

The amendment filed May 9, 2005 has been received and entered. Claim 1 contains the limitation "a fourth lightly doped region of the second type adjacent to the first doped region and beneath the gate". It should be noted that this limitation should have been underlined since it was added to claim by this amendment. Also, claim 5 has been substantially amended but contains no markings.

Claim Objections

Claims 1, 9, 15, and 23 are objected to because of the following informalities:

Regarding claim 1, the limitation "and both sides of the gate" is objected to. It is suggested that Applicant amend the claim to read "and on both sides of the gate". Note claims 9, 15, and 23 have similar problems.

Appropriate correction is required.

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 5 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

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Regarding claim 5, it is unclear what is meant by claim 5 since it depends from a cancelled claim. Furthermore, original claim 4 was not a method claim.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-3, 7, 15-17, 19, and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Smayling et al. (US Pat. 5,275,961, hereinafter Smayling) in view of Back (US Pat. 6,465,845).

Regarding claims 1, 7, 15, and 21, Figure 16g of Smayling discloses a high voltage device comprising: a substrate 152; first and second wells (630 and 626, respectively) respectively of a first type (p-type) and a second type (n-type) in the substrate; a gate 634 formed on a junction between the first and second wells, without a field oxide between the gate and the first and second wells; first and second doped regions (640 and 642, respectively), respectively formed in the first and second wells and on both sides of the gate; a third doped region 644 of the first type in the first well; and a fourth lightly doped region 636 of the second type adjacent to the first doped region and beneath the gate. Smayling does not appear to disclose the third doped region adjacent to the first doped region. Figure 3I of Baek discloses a high voltage device with first and second wells (34 and 33, respectively) of opposite conductivity type, first and second

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regions (36 and 37, respectively) in the first and second wells, and a third doped region 38 adjacent the first region. In view of such teaching, it would have been obvious to the ordinary artisan at the time the invention was made to modify the invention of Smayling by having the third doped region adjacent the first doped region as disclosed by Baek. As disclosed in Figure 16h of Smayling, the first and third regions (640 and 644) are connected to the same metal layer by two separate contacts, and are therefore shorted together. Since they are already shorted, placing the regions adjacent to one another so that they can be contacted by a single contact would decrease the lateral space occupied by the device. Decreasing device size is a well-known industry goal. Regarding claim 15, Smayling also discloses the method of making the above device.

Regarding claims 2 and 16, Figure 16g of Smayling discloses field oxides 210 isolating the high voltage device from other devices on the substrate.

Regarding claims 3 and 17, Figure 16g of Smayling discloses a gate oxide 218 on the substrate, a conducting layer 634 on the gate oxide, and spacers 250 on two sides of the gate oxide and conducting layer.

Regarding claim 19, Figure 16g of Smayling discloses there is a spacing of the second doped region 642 to the gate 634.

Allowable Subject Matter

Claims 8 and 22 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

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Claims 9-11, 13, 23-25, and 27 would be allowable if rewritten or amended to overcome the claim objections set forth in this Office action.

The following is a statement of reasons for the indication of allowable subject matter:

Regarding claims 8 and 22, the prior art of record, either singularly or in combination, does not disclose or suggest the combination of limitations including the first and second types are respectively N and P types and the high voltage device further comprises a N+ buried layer in the substrate and beneath the first and second wells.

Regarding claims 9 and 23, the prior art of record, either singularly or in combination, does not disclose or suggest the combination of limitations including a N+ buried layer in the P substrate; two second P+ doped regions respectively formed in the second N and P wells, and both sides of the second gate; a second N+ doped region in the second N well and adjacent to the second P+ doped region in the second N well; and a P lightly doped region adjacent to the second P+ doped region in the second N well and beneath the second gate.

Response to Arguments

Applicant's arguments with respect to claims 1 and 15 have been considered but are moot in view of the new ground(s) of rejection.

Applicant's arguments (see second page of "Remarks" (page 9)), filed May 9, 2005, with respect to the 112, 1st paragraph new matter rejections have been fully considered and are persuasive. Therefore, these rejections have been withdrawn.

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew C. Landau whose telephone number is (571) 272-1731.

The examiner can normally be reached from 8:30 AM - 5:30 PM. If attempts to reach the

examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached

on (571) 272-1664. The fax phone numbers for the organization where this application or

proceeding is assigned are (703) 872-9306 for regular communications and (703) 872-9306 for

After Final communications.

Information regarding the status of an application may be obtained from the Patent

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system, see http://pair-direct.uspto.gov. Should any questions arise regarding access to the

Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Matthew C. Landau

Examiner

TOTA THOMAS May 26, 2005

SUPERVISORY PATENT EXAMINEER